Zero-field splitting of Kondo resonances in a carbon nanotube quantum dot.

J. Nygard, W. F. Koehl, N. Mason, L. Di Carlo, and C. M.Marcus

condmat/0410467

Low-temperature (mK) electron transport measurements on CVD-grown SWCNTs (d~1-3 nm) on SiO₂ substrate; Au electrodes thermally evaporated

Kondo resonance

Splitting of Kondo peaks at zero magnetic field

Kondo Effect in QDs

Screening of a single-spin by conduction electrons Formation of a singlet state (S=0) induced by spin fluctuations

Narrow (order of $k_B T_K$) resonance at E_F leads to conductance increase, opening of a new transport channel (at T=0, G=e²/h, unitary limit)



- Energy scales:
 - Γ = level broadening
 - $\Delta \epsilon$ = level spacing
 - U = charging energy
 - $k_{\rm B}T$ = temperature

$G(T \sim 300 \text{ K}, \text{V}_{\text{G}}) \sim 1.8 \text{ e}^2/\text{h} \longrightarrow \text{metallic tubes}$

S=1/2



FIG. 1: (a) Schematic of nanotube device, comprising a single-wall carbon nanotube, two Cr/Au electrodes (source and drain), and a doped Si gate underneath the SiO₂ cap layer. (b) Differential conductance dI/dV as a function of source-drain voltage V for gate voltages $V_g = -5.10$ V (solid) and $V_g = -5.15$ V (dashed) at temperature $T_{\rm el} = 80$ mK. (c) Plot of dI/dV as a function of V and V_g (color online). The dashed line corresponds to the solid trace in (b).



FIG. 2: (a) Temperature dependence of the zero-bias conductance G for the resonance shown in Fig. 1b ($V_g = -5.10$ V). (b)-(e) dI/dV as a function of V for the same resonance, at temperatures 80 (b), 145 (c), 220 (d), and 550 mK (e).

Splitting at all fields !



FIG. 3: (a) Magnetic field dependence of dI/dV as a function of source-drain voltage V for the peak in Fig. 2(b) at base $T_{\rm el} = 80$ mK. The applied magnetic field B was increased from -0.5 T (dashed) over 0 T (thick) to 0.5 T (dotted) in steps of 0.1 T. Subsequent curves are offset by 0.01 e^2/h for clarity. (b) Peak splitting ΔV as a function of applied magnetic field B for the data in (a) (solid) and another series where B was swept from 0.5 T to -0.3 T (open).

....the Kondo resonances in this study has probed the effect of a magnetic impurity (iron-containing catalyst material used to grow the CNT) on electron transport in a carbon nanotube device.....

Possible consequences for spin-dependent transport (GMR)?

Difficult to see Kondo effect in CNTs contacted by FM electrodes because of bad contacts (low transmission), see e.g. K. Tsukagoshi et al. Nature 401, 573 (1999)